

## TRIPLE DIFFUSED PLANER TYPE HIGH SPEED SWITCHING

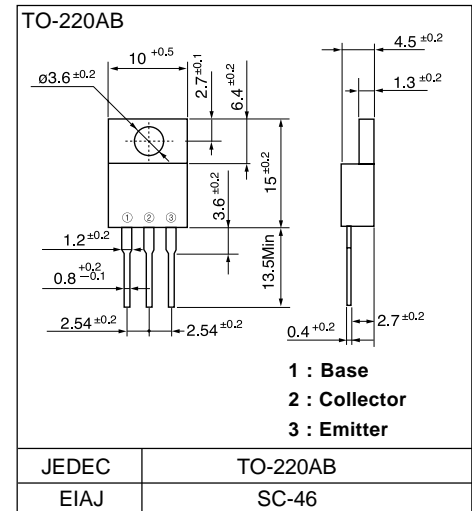
### ■ Features

- High speed switching
- Low saturation voltage
- High reliability

### ■ Applications

- Switching regulators
- Ultrasonic generators
- High frequency inverters
- General purpose power amplifiers

### ■ Outline Drawings



### ■ Maximum ratings and characteristics

#### ● Absolute maximum ratings (T<sub>c</sub>=25°C unless otherwise specified)

Item	Symbol	Ratings	Unit
Collector-Base voltage	V <sub>CB0</sub>	150	V
Collector-Emitter voltage	V <sub>CE0</sub>	80	V
Collector-Emitter voltage	V <sub>CE0(SUS)</sub>	-	V
Emitter-Base voltage	V <sub>EB0</sub>	7	V
Collector current	I <sub>C</sub>	7	A
Base current	I <sub>B</sub>	2	A
Collector power dissipation	P <sub>C</sub>	50	W
Operating junction temperature	T <sub>j</sub>	+150	°C
Storage temperature	T <sub>stg</sub>	-55 to +150	°C

#### ● Electrical characteristics (T<sub>c</sub> =25°C unless otherwise specified)

Item	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Collector-Base voltage	V <sub>CB0</sub>	I <sub>CBO</sub> = 0.1mA	150			V
Collector-Emitter voltage	V <sub>CE0</sub>	I <sub>CE0</sub> = 10mA	80			V
Collector-Emitter voltage	V <sub>CE0(SUS)</sub>	I <sub>C</sub> = A	-	-		V
Emitter-Base voltage	V <sub>EB0</sub>	I <sub>EBO</sub> = 0.1mA	7	-		V
Collector-Base leakage current	I <sub>CBO</sub>	V <sub>CB0</sub> = 150V		-	0.1	mA
Emitter-Base leakage current	I <sub>EBO</sub>	V <sub>EB0</sub> = 7V		-	0.1	mA
D.C. current gain	h <sub>FE</sub>	I <sub>C</sub> = 4A, V <sub>CE</sub> = 1V	30			
Collector-Emitter saturation voltage	V <sub>CE(Sat)</sub>	I <sub>C</sub> = 4A, I <sub>B</sub> = 0.4A			0.5	V
Base-Emitter saturation voltage	V <sub>BE(Sat)</sub>				1.2	V
*1	t <sub>on</sub>	I <sub>C</sub> = 4A, I <sub>B1</sub> = 0.4A			0.5	μs
Switching time	t <sub>stg</sub>	I <sub>B2</sub> = -0.4A, R <sub>L</sub> = 5 ohm			2.5	μs
	t <sub>f</sub>	P <sub>w</sub> = 20μs Duty=<2%			0.3	μs

#### ● Thermal characteristics

Item	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Thermal resistance	R <sub>th(j-c)</sub>	Junction to case			2.5	°C/W

■ Characteristics

